

# TrenchT2™ Power MOSFET

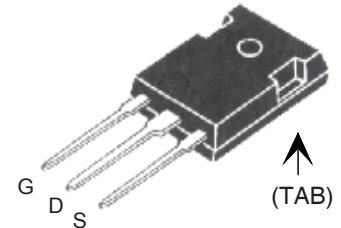
## IXTH300N04T2

$$\begin{aligned} V_{DSS} &= 40V \\ I_{D25} &= 300A \\ R_{DS(on)} &\leq 2.5m\Omega \end{aligned}$$

N-Channel Enhancement Mode  
Avalanche Rated



TO-247



G = Gate      D = Drain  
S = Source      TAB = Drain

### Features

- International standard package
- 175°C Operating Temperature
- High current handling capability
- Avalanche Rated
- Low  $R_{DS(on)}$

### Advantages

- Easy to mount
- Space savings
- High power density

### Applications

- Synchronous Buck Converters
- High Current Switching Power Supplies
- Battery Powered Electric Motors
- Resonant-mode power supplies
- Electronics Ballast Application
- Class D Audio Amplifiers

| Symbol     | Test Conditions                                                       | Maximum Ratings |                  |
|------------|-----------------------------------------------------------------------|-----------------|------------------|
| $V_{DSS}$  | $T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$                       | 40              | V                |
| $V_{DGR}$  | $T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$ , $R_{GS} = 1M\Omega$ | 40              | V                |
| $V_{GSM}$  | Transient                                                             | $\pm 20$        | V                |
| $I_{D25}$  | $T_C = 25^\circ\text{C}$                                              | 300             | A                |
| $I_{LRMS}$ | Lead Current Limit, RMS                                               | 160             | A                |
| $I_{DM}$   | $T_C = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$            | 900             | A                |
| $I_A$      | $T_C = 25^\circ\text{C}$                                              | 100             | A                |
| $E_{AS}$   | $T_C = 25^\circ\text{C}$                                              | 600             | mJ               |
| $P_D$      | $T_C = 25^\circ\text{C}$                                              | 480             | W                |
| $T_J$      |                                                                       | -55 ... +175    | $^\circ\text{C}$ |
| $T_{JM}$   |                                                                       | 175             | $^\circ\text{C}$ |
| $T_{stg}$  |                                                                       | -55 ... +175    | $^\circ\text{C}$ |
| $T_L$      | 1.6mm (0.062in.) from case for 10s                                    | 300             | $^\circ\text{C}$ |
| $T_{sold}$ | Plastic body for 10 seconds                                           | 260             | $^\circ\text{C}$ |
| $M_d$      | Mounting torque                                                       | 1.13 / 10       | Nm/lb.in.        |
| Weight     |                                                                       | 6               | g                |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ unless otherwise specified) | Characteristic Values |      |                          |
|--------------|---------------------------------------------------------------------------|-----------------------|------|--------------------------|
|              |                                                                           | Min.                  | Typ. | Max.                     |
| $BV_{DSS}$   | $V_{GS} = 0V$ , $I_D = 250\mu A$                                          | 40                    |      | V                        |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 250\mu A$                                      | 2.0                   |      | 4.0 V                    |
| $I_{GSS}$    | $V_{GS} = \pm 20V$ , $V_{DS} = 0V$                                        |                       |      | $\pm 200$ nA             |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$<br>$V_{GS} = 0V$ $T_J = 150^\circ\text{C}$             |                       |      | 5 $\mu A$<br>150 $\mu A$ |
| $R_{DS(on)}$ | $V_{GS} = 10V$ , $I_D = 50A$ , Notes 1, 2                                 |                       |      | 2.5 m $\Omega$           |

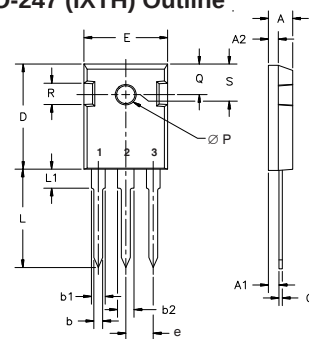
| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified)                                                                  | Characteristic Values |      |                         |
|--------------|----------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|-------------------------|
|              |                                                                                                                                              | Min.                  | Typ. | Max.                    |
| $g_{fs}$     | $V_{DS} = 10\text{V}$ , $I_D = 60\text{A}$ , Note 1                                                                                          | 55                    | 94   | S                       |
| $C_{iss}$    | $V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$                                                                             |                       | 10.7 | nF                      |
| $C_{oss}$    |                                                                                                                                              |                       | 1630 | pF                      |
| $C_{rss}$    |                                                                                                                                              |                       | 263  | pF                      |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 100\text{A}$<br>$R_G = 2\Omega$ (External) |                       | 22   | ns                      |
| $t_r$        |                                                                                                                                              |                       | 17   | ns                      |
| $t_{d(off)}$ |                                                                                                                                              |                       | 32   | ns                      |
| $t_f$        |                                                                                                                                              |                       | 13   | ns                      |
| $Q_{g(on)}$  | $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$                                                             |                       | 145  | nC                      |
| $Q_{gs}$     |                                                                                                                                              |                       | 44   | nC                      |
| $Q_{gd}$     |                                                                                                                                              |                       | 36   | nC                      |
| $R_{thJC}$   |                                                                                                                                              |                       |      | 0.31 $^\circ\text{C/W}$ |
| $R_{thCH}$   |                                                                                                                                              | 0.21                  |      | $^\circ\text{C/W}$      |

## Source-Drain Diode

| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified)                            | Characteristic Values |      |        |
|----------|--------------------------------------------------------------------------------------------------------|-----------------------|------|--------|
|          |                                                                                                        | Min.                  | Typ. | Max.   |
| $I_S$    | $V_{GS} = 0\text{V}$                                                                                   |                       |      | 300 A  |
| $I_{SM}$ | Repetitive, Pulse width limited by $T_{JM}$                                                            |                       |      | 1000 A |
| $V_{SD}$ | $I_F = 100\text{A}$ , $V_{GS} = 0\text{V}$ , Note 1                                                    |                       |      | 1.3 V  |
| $t_{rr}$ | $I_F = 150\text{A}$ , $V_{GS} = 0\text{V}$<br>$-di/dt = 100\text{A}/\mu\text{s}$<br>$V_R = 20\text{V}$ |                       | 53   | ns     |
| $I_{RM}$ |                                                                                                        |                       | 1.8  | A      |
| $Q_{RM}$ |                                                                                                        |                       | 47.7 | nC     |

Note 1: Pulse test,  $t \leq 300\mu\text{s}$ ; duty cycle,  $d \leq 2\%$ .

## TO-247 (IXTH) Outline



Terminals: 1 - Gate 2 - Drain

| Dim.           | Millimeter |       | Inches |       |
|----------------|------------|-------|--------|-------|
|                | Min.       | Max.  | Min.   | Max.  |
| A              | 4.7        | 5.3   | .185   | .209  |
| A <sub>1</sub> | 2.2        | 2.54  | .087   | .102  |
| A <sub>2</sub> | 2.2        | 2.6   | .059   | .098  |
| b              | 1.0        | 1.4   | .040   | .055  |
| b <sub>1</sub> | 1.65       | 2.13  | .065   | .084  |
| b <sub>2</sub> | 2.87       | 3.12  | .113   | .123  |
| C              | .4         | .8    | .016   | .031  |
| D              | 20.80      | 21.46 | .819   | .845  |
| E              | 15.75      | 16.26 | .610   | .640  |
| e              | 5.20       | 5.72  | 0.205  | 0.225 |
| L              | 19.81      | 20.32 | .780   | .800  |
| L <sub>1</sub> |            | 4.50  |        | .177  |
| ØP             | 3.55       | 3.65  | .140   | .144  |
| Q              | 5.89       | 6.40  | 0.232  | 0.252 |
| R              | 4.32       | 5.49  | .170   | .216  |

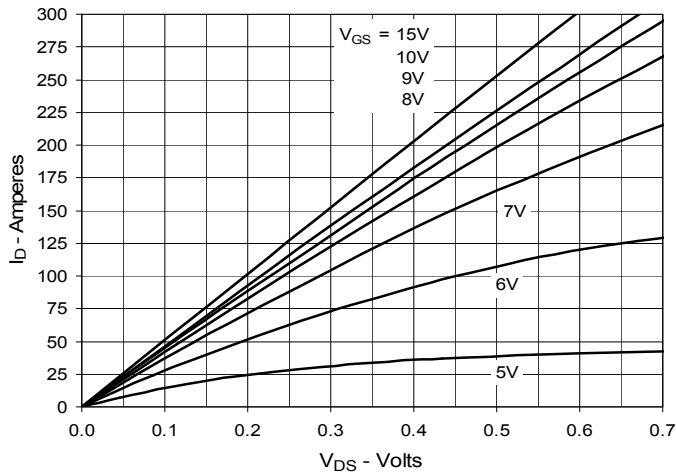
## PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a pre-production design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

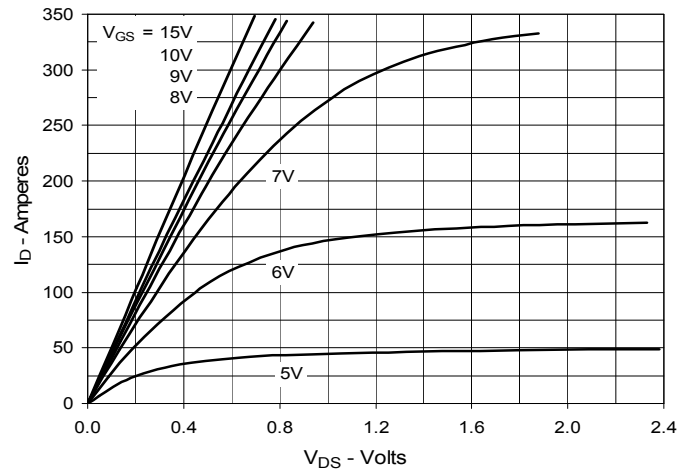
IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065 B1 6,683,344 6,727,585 7,005,734 B2 7,157,338B2  
by one or more of the following U.S. patents: 4,850,072 5,017,508 5,063,307 5,381,025 6,259,123 B1 6,534,343 6,710,405 B2 6,759,692 7,063,975 B2  
4,881,106 5,034,796 5,187,117 5,486,715 6,306,728 B1 6,583,505 6,710,463 6,771,478 B2 7,071,537

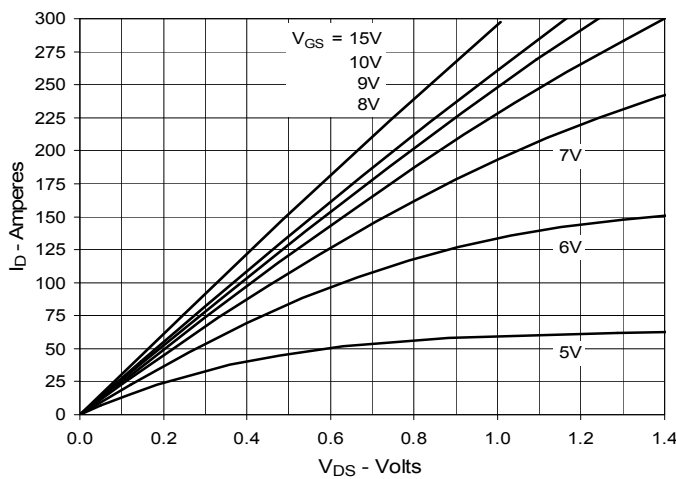
**Fig. 1. Output Characteristics  
@ 25°C**



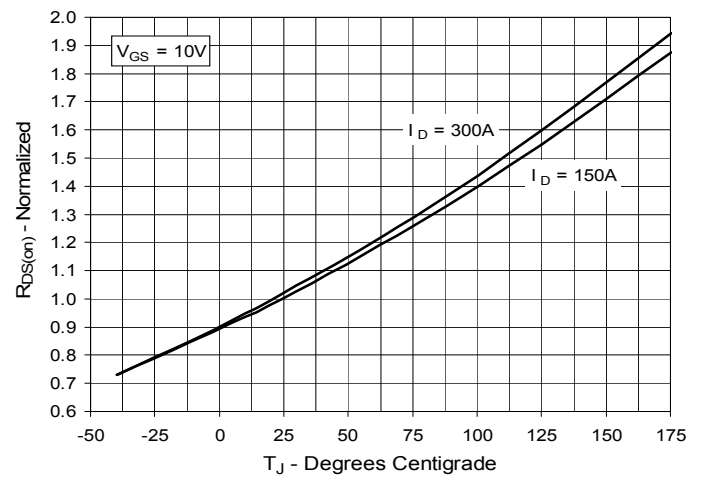
**Fig. 2. Extended Output Characteristics  
@ 25°C**



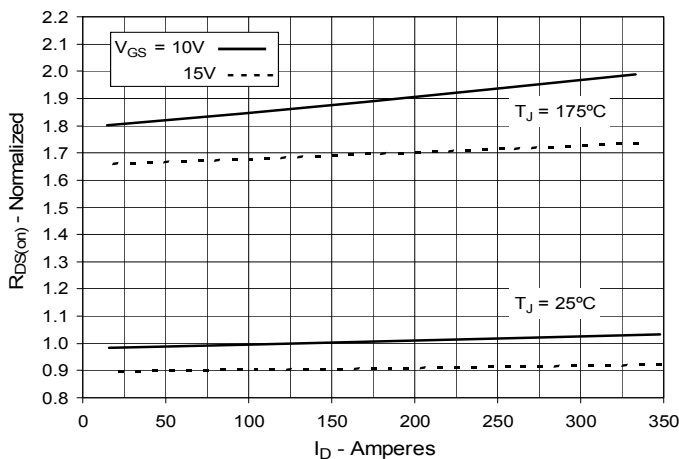
**Fig. 3. Output Characteristics  
@ 150°C**



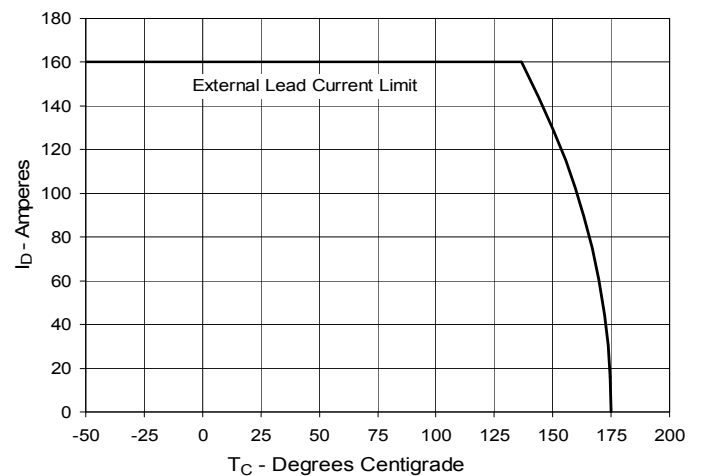
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 150\text{A}$  Value  
vs. Junction Temperature**



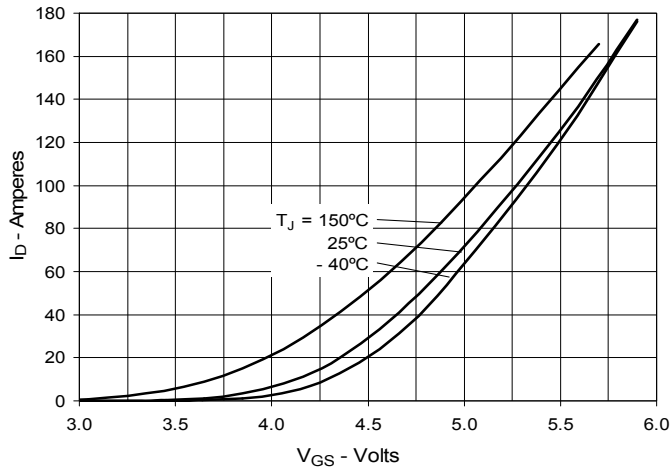
**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 150\text{A}$  Value  
vs. Drain Current**



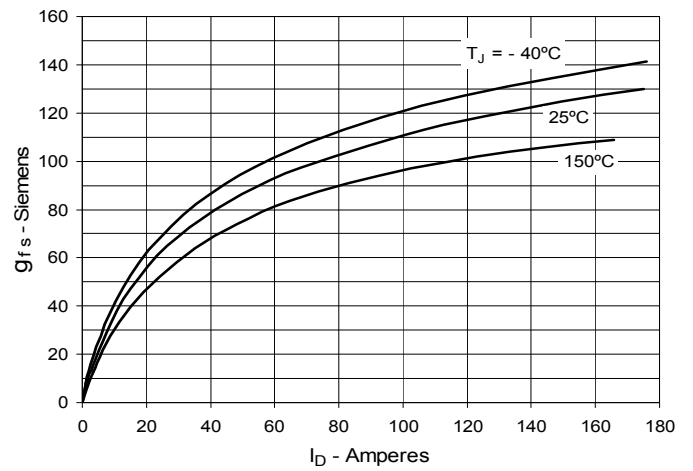
**Fig. 6. Drain Current vs. Case Temperature**



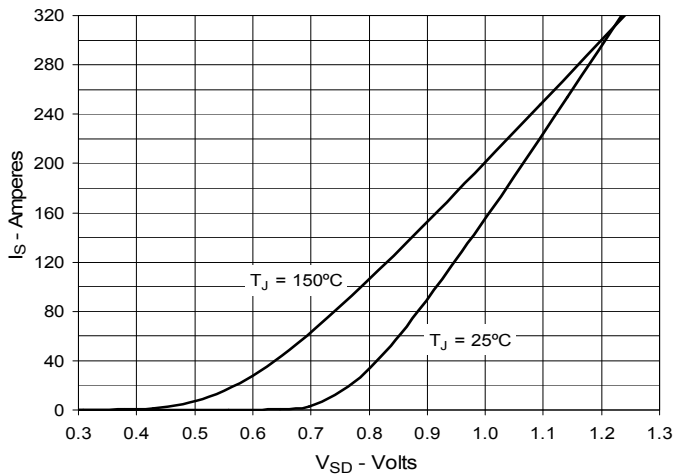
**Fig. 7. Input Admittance**



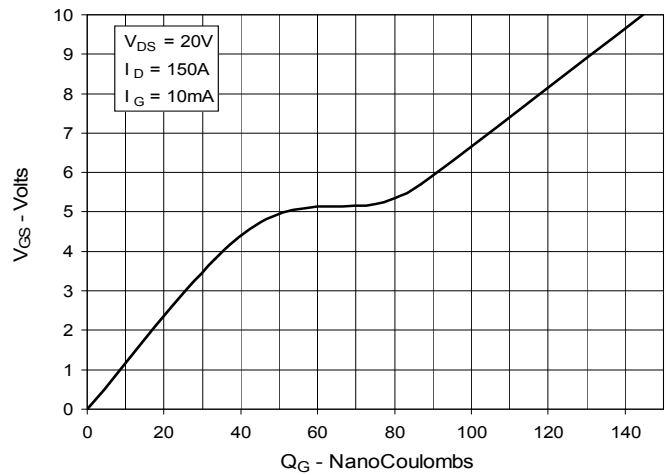
**Fig. 8. Transconductance**



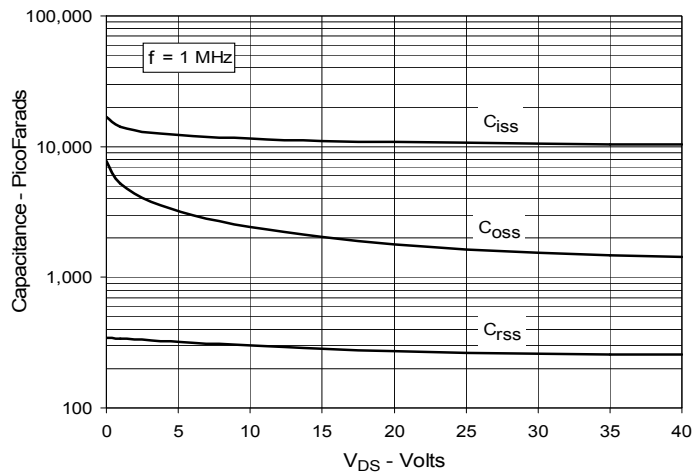
**Fig. 9. Forward Voltage Drop of Intrinsic Diode**



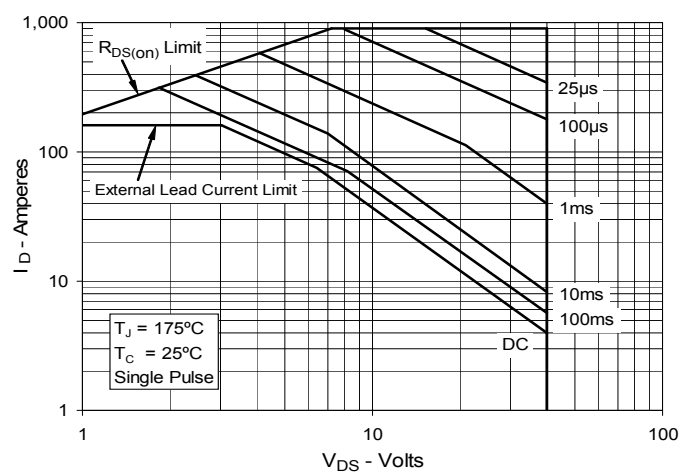
**Fig. 10. Gate Charge**



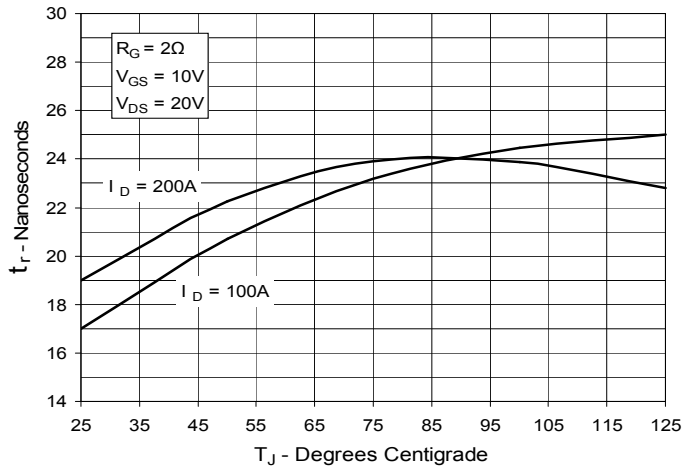
**Fig. 11. Capacitance**



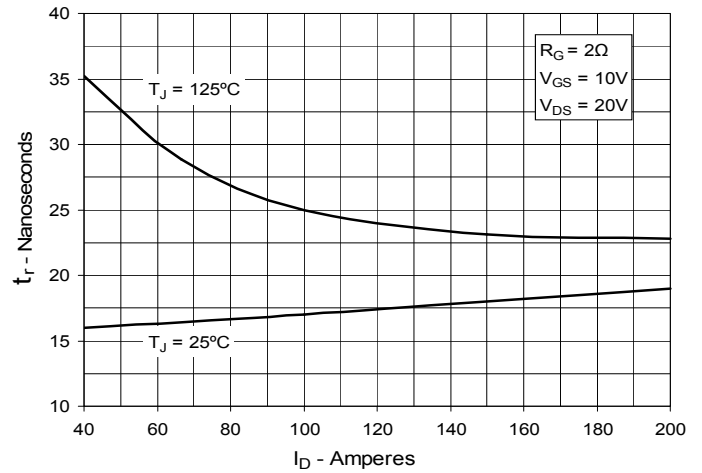
**Fig. 12. Forward-Bias Safe Operating Area**



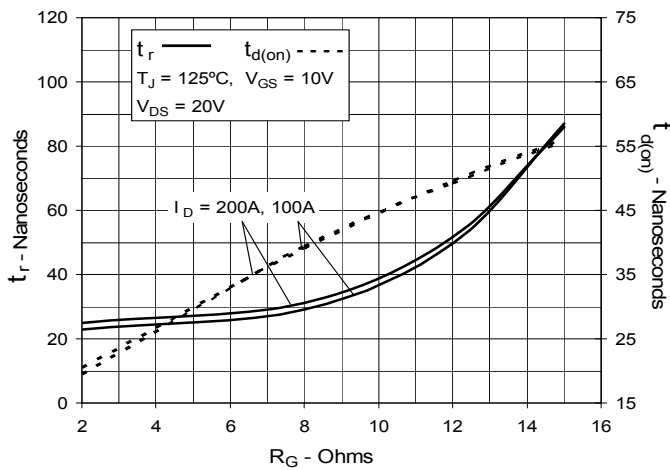
**Fig. 13. Resistive Turn-on  
Rise Time vs. Junction Temperature**



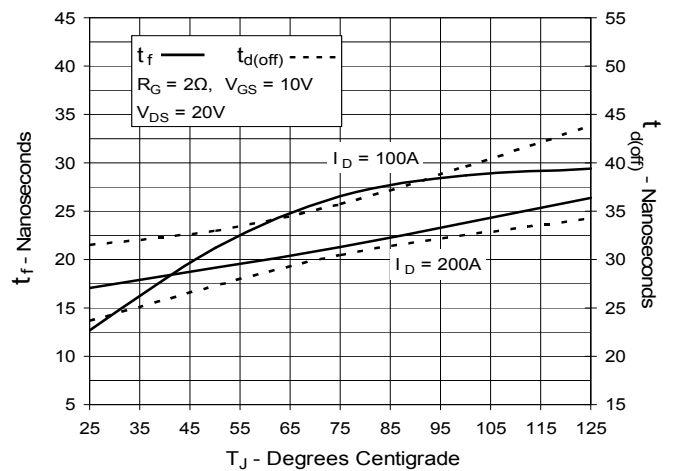
**Fig. 14. Resistive Turn-on  
Rise Time vs. Drain Current**



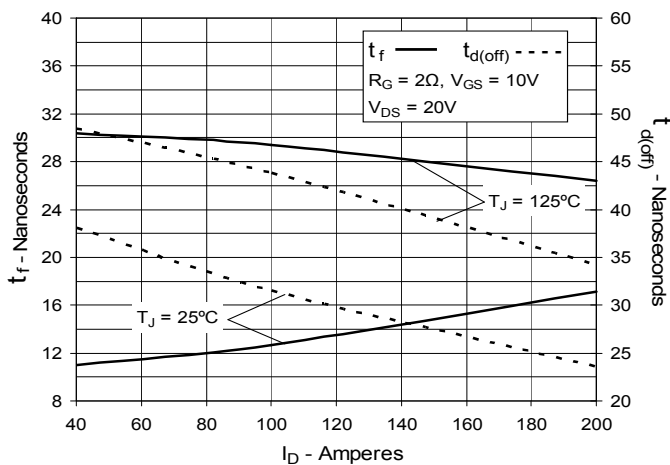
**Fig. 15. Resistive Turn-on  
Switching Times vs. Gate Resistance**



**Fig. 16. Resistive Turn-off  
Switching Times vs. Junction Temperature**



**Fig. 17. Resistive Turn-off  
Switching Times vs. Drain Current**



**Fig. 18. Resistive Turn-off  
Switching Times vs. Gate Resistance**

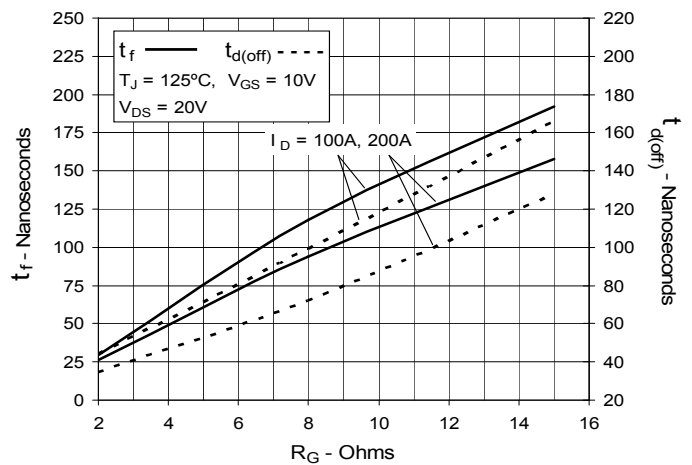
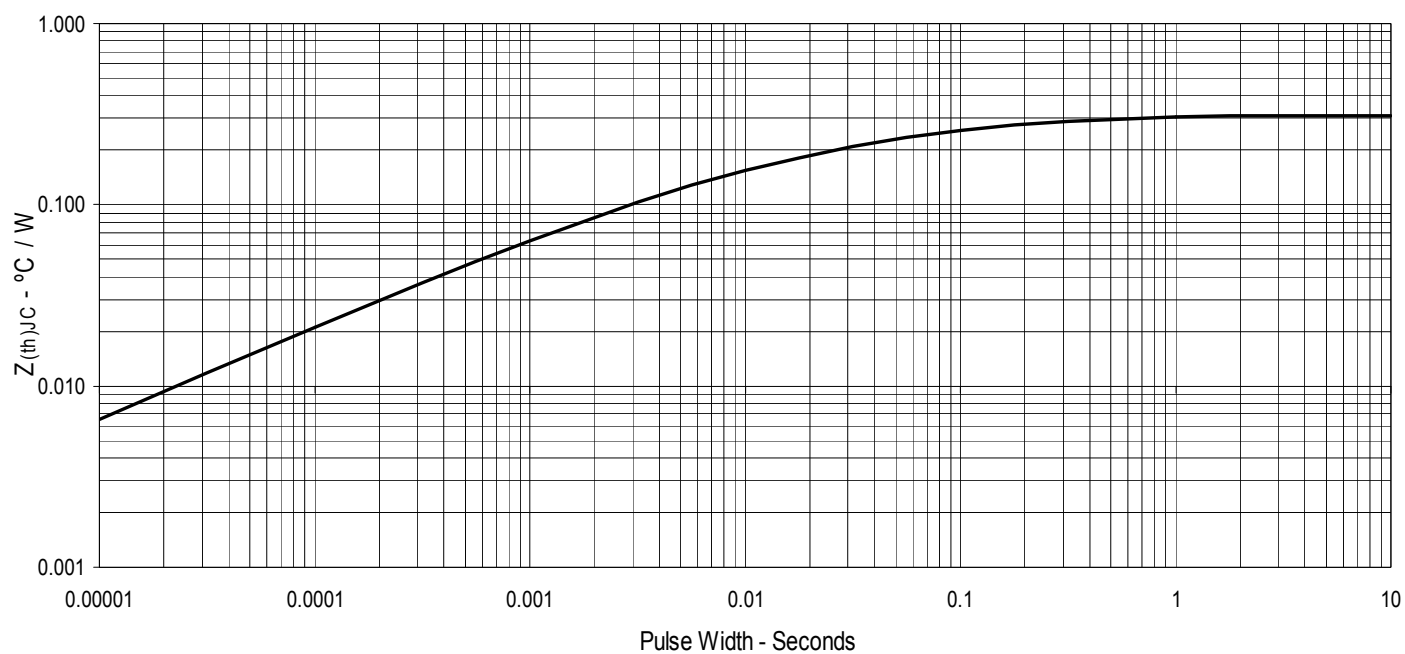


Fig. 19. Maximum Transient Thermal Impedance





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